



60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-16 A

Features

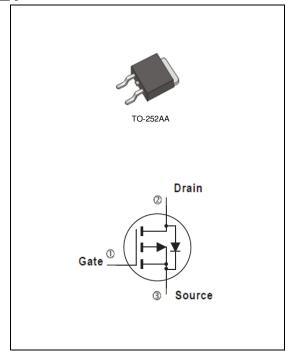
- $R_{DS(ON)}$, V_{GS} @-10V, I_{D} @-8A<48m Ω
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_{D} @-4A<65m Ω
- · High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-252AA Approx. Weight: 0.0104 ounces, 0.297grams



$\textbf{Maximum Ratings and Thermal Characteristics} \; (T_{A} = 25 ^{\circ} C \; \text{unless otherwise noted})$

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|-----------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | -60 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current (Note 4) | T _C =25°C | I _D | -16 | | |
| | T _C =100°C | | -10 | Α | |
| Pulsed Drain Current (Note 1) | T _C =25°C | I _{DM} | -64 | | |
| Power Dissipation | T _C =25°C | Po | 25 | 147 | |
| | T _C =100°C | | 10 | W | |
| Continuous Drain Current (Note 4) | T _A =25°C | I _D | -5 | | |
| | T _A =70°C | | -4 | Α | |
| Power Dissipation | T _A =25°C | Po | 2 | | |
| | T _A =70°C | | 1.3 | W | |
| Single Pulse Avalanche Energy (Note 6) | | E _{AS} | 51 | mJ | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | °C | |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{\theta JC}$ | 5 | °C/W | |
| | Junction to Ambient | $R_{	heta JA}$ | 62.5 | | |

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|--|------|-------|--------------|-------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V_{GS} =0V, I_D =-250uA | -60 | - | - | V | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=-250uA$ | -1 | -1.7 | -2.5 | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V_{GS} =-10V, I_D =-8A | - | 40 | 48 | mΩ | |
| | | V_{GS} =-4.5V, I_{D} =-4A | - | 55 | 65 | | |
| Zero Gate Voltage Drain Current | I_{DSS} | V_{DS} =-60V, V_{GS} =0V | - | - | -1 | uA | |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | - | - | <u>+</u> 100 | nA | |
| Dynamic (Note 7) | | | | | | | |
| Total Gate Charge | Q_g | V_{DS} =-30V, I_{D} =-8A, V_{GS} =-10V (Note 2,3) | - | 22 | - | nC | |
| Gate-Source Charge | Q_gs | | - | 4.1 | - | | |
| Gate-Drain Charge | Q_gd | | - | 5.2 | - | | |
| Input Capacitance | Ciss | V _{DS} =-30V, V _{GS} =0V, | - | 1256 | - | pF | |
| Output Capacitance | Coss | | - | 87 | - | | |
| Reverse Transfer Capacitance | Crss | I = I IVITIZ | - | 59 | - | | |
| Turn-On Delay Time | td _(on) | \/ 00\/ I 1A | - | 13 | - | | |
| Turn-On Rise Time | t _r | V_{DD} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 2,3) | - | 42 | - | ns | |
| Turn-Off Delay Time | $td_{(off)}$ | | - | 65 | - | | |
| Turn-Off Fall Time | t _f | | - | 16 | - | | |
| Drain-Source Diode | | | | | | | |
| Maximum Continuous Drain-Source | | | - | - | -16 | А | |
| Diode Forward Current | I _S | | | | | | |
| Reverse Recovery Time | V_{SD} | I _S =-1A, V _{GS} =0V | - | -0.72 | -1 | V | |

NOTES:

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. L=0.1mH, I_{AS} =-32A, V_{GS} =-10V, V_{DS} =-25V, R_{G} =25 ohm.
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

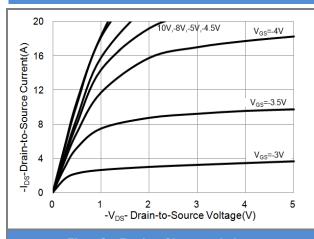


Fig.1 On-Region Characteristics

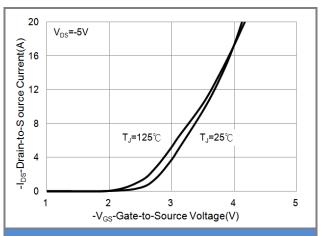


Fig.2 Transfer Characteristics

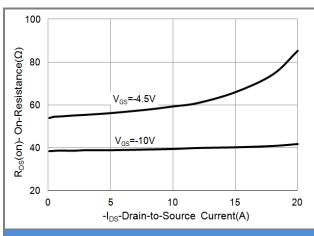


Fig.3 On-Resistance vs. Drain Current

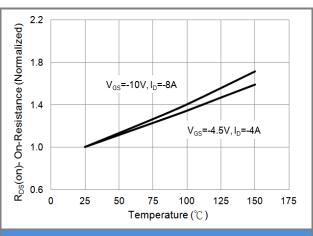


Fig.4 On-Resistance vs. Junction temperature

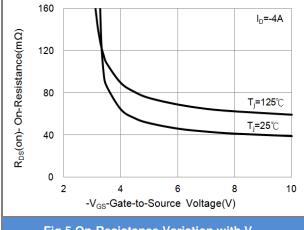


Fig.5 On-Resistance Variation with V_{GS}

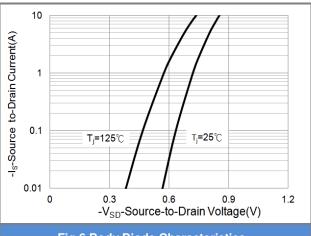


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

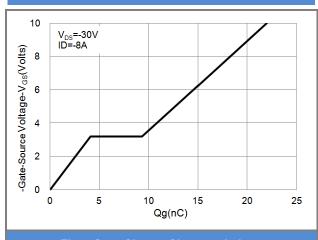


Fig.7 Gate-Charge Characteristics

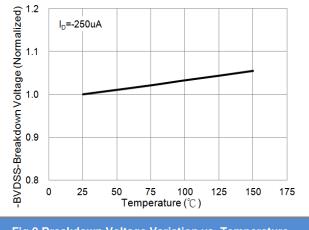


Fig.8 Breakdown Voltage Variation vs. Temperature

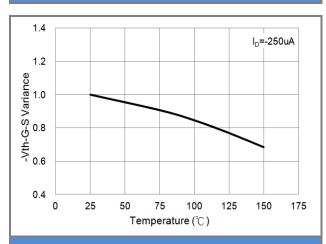


Fig.9 Threshold Voltage Variation with Temperature

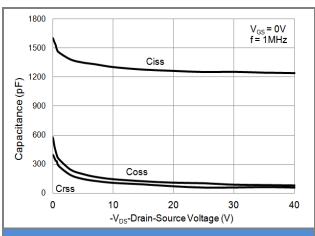
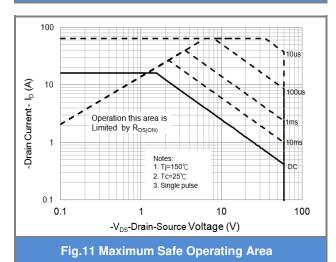


Fig.10 Capacitance vs. Drain-Source Voltage







TYPICAL CHARACTERISTIC CURVES

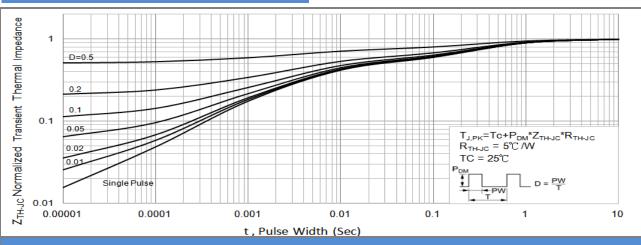


Fig.12 Normalized Thermal Transient Impedance

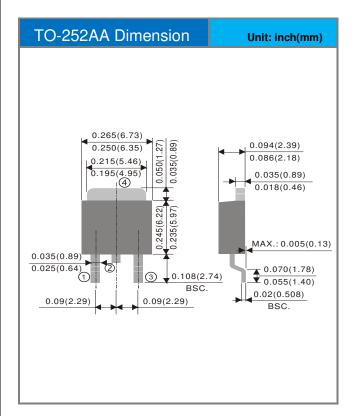


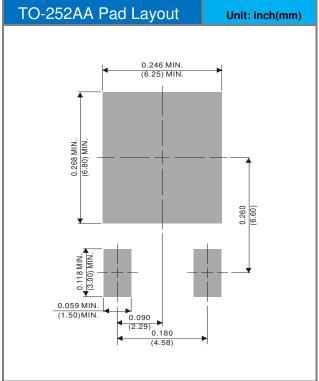


Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|----------------------|--------------|---------------------|---------|--------------|--|
| PJD16P06A_L2_00001 | TO-252AA | 3,000pcs / 13" reel | D16P06A | Halogen free | |

Packaging Information & Mounting Pad Layout









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